

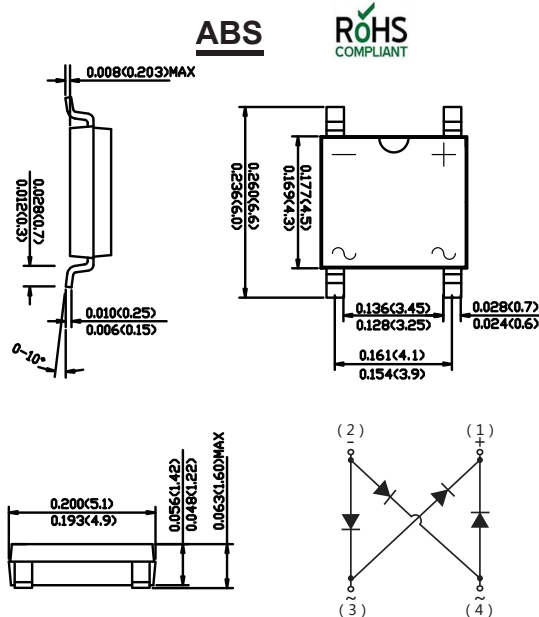
GLASS PASSIVATED SURFACE MOUNT BRIDGE RECTIFIERS

Features

- ◆ Glass Passivated Chip Junction
- ◆ Reverse Voltage - 100 to 1000 V
- ◆ Forward Current- 2.0 A
- ◆ Fast reverse recovery time
- ◆ Designed for Surface Mount Application

Mechanical Data

Case : JEDEC ABS molded plastic body
 Terminals : Solderable per MIL-STD-750, Method 2026
 Polarity : Polarity symbol marking on body Mounting
 Position : Any
 Weight : 0.0031 ounce, 0.088 grams



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	Symbols	MDD RABS21	MDD RABS22	MDD RABS24	MDD RABS26	MDD RABS28	MDD RABS210	Units
Marking Code								
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	100	200	400	600	800	1000	V
Average Rectified Output Current at $T_c = 115^\circ\text{C}$	I_O	2.0						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	50						A
Maximum Forward Voltage at 2.0 A	V_F	1.3						V
Maximum DC Reverse Current @ $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_a = 125^\circ\text{C}$	I_R	5.0 200						μA
Typical Junction Capacitance (Note 1)	C_j	40						pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	50						$^\circ\text{C/W}$
Maximum Reverse Recovery Time (Note 3)	t_{rr}	500						ns
Operating and Storage Temperature Range	T_j, T_{stg}	$-55 \sim +150$						$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with $4 \times 1.5 \times 1.5$ (3.81 × 3.81 cm) copper pad areas.

3. Measured with $I = 0.5\text{ A}$, $I = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$.

Typical Characteristics

Fig.1 Average Rectified Output Current Derating Curve

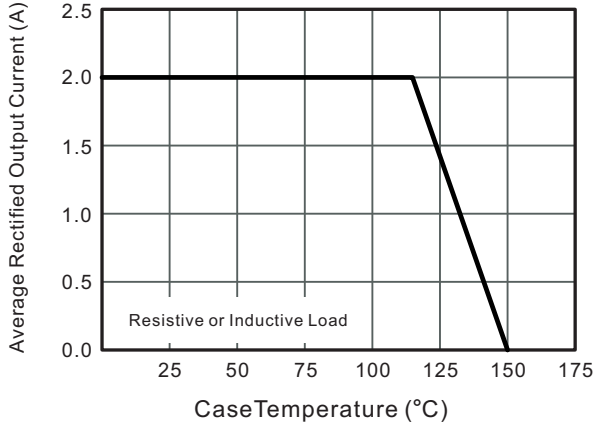


Fig.2 Typical Reverse Characteristics

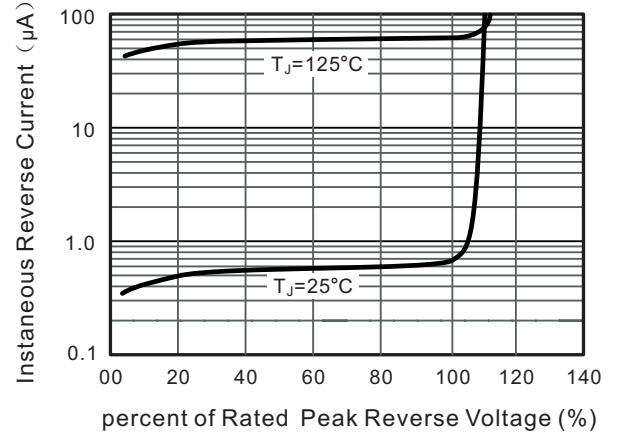


Fig.3 Typical Instantaneous Forward Characteristics

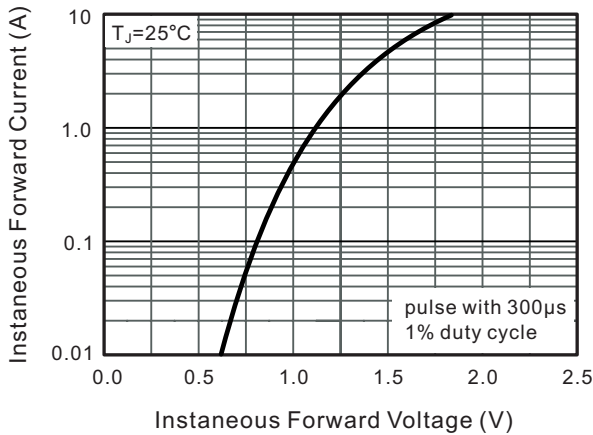


Fig.4 Typical Junction Capacitance

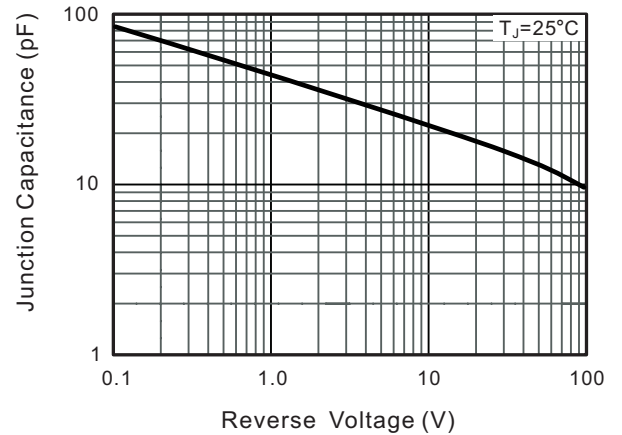
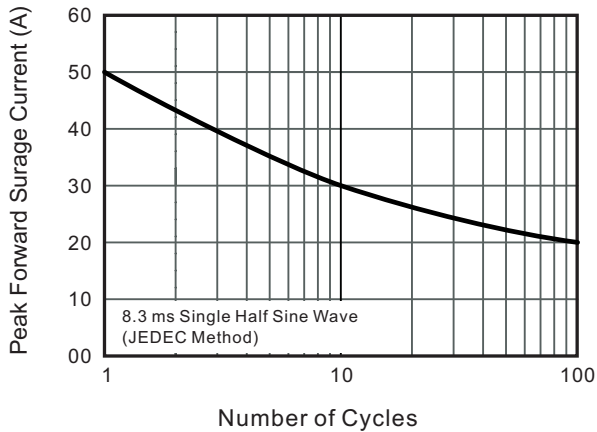
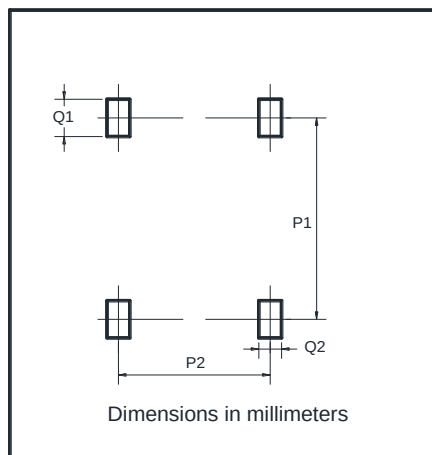


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



The curve above is for reference only.

Suggested Pad Layout



Dim	Min
P1	5.72
P2	4.00
Q1	1.00
Q2	0.90